

RGW60TS65DHR

650V 30A Field Stop Trench IGBT

V _{CES}	650V
Ι _{C (100°C)}	30A
V _{CE(sat) (Typ.)}	1.5V
P _D	178W

Features

- 1) AEC-Q101 Qualified
- 2) Low Collector Emitter Saturation Voltage
- 3) Low Switching Loss & Soft Switching
- 4) Built in Very Fast & Soft Recovery FRD
- 5) Pb free Lead Plating ; RoHS Compliant

Application

Automotive

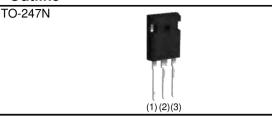
On & Off Board Chargers

DC-DC Converters

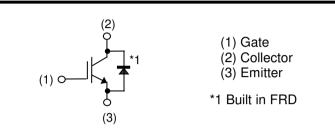
PFC

Industrial Inverter

Outline



Inner Circuit



Packaging Specifications

	Packaging	Tube
	Reel Size (mm)	-
Tuno	Tape Width (mm)	-
Туре	Basic Ordering Unit (pcs)	450
	Packing Code	C11
	Marking	RGW60TS65D

•Absolute Maximum Ratings (at T_C = 25°C unless otherwise specified)

Parameter		Symbol	Value	Unit
Collector - Emitter Voltage		V _{CES}	650	V
Gate - Emitter Voltage		V _{GES}	±30	V
Collector Current	$T_{\rm C} = 25^{\circ}{\rm C}$	Ι _C	64	Α
Collector Current	$T_{\rm C} = 100^{\circ}{\rm C}$	Ι _C	39	Α
Pulsed Collector Current		I _{CP} *1	120	Α
Diode Forward Current	$T_{\rm C} = 25^{\circ}{\rm C}$	I _F	41	Α
	$T_{C} = 100^{\circ}C$	I _F	25	Α
Diode Pulsed Forward Current		I _{FP} ^{*1}	120	Α
Dower Dissignation	$T_{\rm C} = 25^{\circ}{\rm C}$	P _D	178	W
Power Dissipation	$T_{\rm C} = 100^{\circ}{\rm C}$	P _D	89	W
Operating Junction Temperature		T _j	-40 to +175	°C
Storage Temperature		T _{stg}	-55 to +175	°C

*1 Pulse width limited by T_{jmax} .

•Thermal Resistance

Baramatar	Symbol	Values			Unit
Parameter	Symbol	Min.	Тур.	Max.	Unit
Thermal Resistance IGBT Junction - Case	$R_{\theta(j\text{-}c)}$	-	-	0.84	°C/W
Thermal Resistance Diode Junction - Case	$R_{\theta(j\text{-}c)}$	-	-	1.62	°C/W

●IGBT Electrical Characteristics (at T_j = 25°C unless otherwise specified)

Parameter	Symbol Conditions		Values			Unit
	Symbol	Conditions	Min.	Тур.	Max.	Unit
Collector - Emitter Breakdown Voltage	BV _{CES}	$I_{\rm C}$ = 10µA, $V_{\rm GE}$ = 0V	650	-	_	V
Collector Cut - off Current	I _{CES}	$V_{CE} = 650V, V_{GE} = 0V$	-	-	10	μA
Gate - Emitter Leakage Current	I _{GES}	$V_{GE} = \pm 30V, V_{CE} = 0V$	-	-	±200	nA
Gate - Emitter Threshold Voltage	$V_{\text{GE(th)}}$	$V_{CE} = 5V, I_{C} = 20.0 \text{mA}$	5.0	6.0	7.0	V
Collector - Emitter Saturation Voltage	V _{CE(sat)}	$I_{C} = 30A, V_{GE} = 15V,$ $T_{j} = 25^{\circ}C$ $T_{j} = 175^{\circ}C$	-	1.5 1.85	1.9 -	V

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•IGBT Electrical Characteristics (at $T_j = 25^{\circ}C$ unless otherwise specified)

Parameter	Symbol Conditions		Unit			
		Conditions	Min.	Тур.	Max.	Unit
Input Capacitance	C _{ies}	$V_{CE} = 30V,$	-	2530	-	
Output Capacitance	C _{oes}	$V_{GE} = 0V,$	-	65	-	pF
Reverse transfer Capacitance	C _{res}	f = 1MHz	-	46	-	
Total Gate Charge	Qg	V _{CE} = 400V,	-	84	-	
Gate - Emitter Charge	Q _{ge}	I _C = 30A,	-	17	-	nC
Gate - Collector Charge	Q _{gc}	V _{GE} = 15V	-	31	-	
Turn - on Delay Time	t _{d(on)}		-	36	-	
Rise Time	t _r	$I_{C} = 15A, V_{CC} = 400V,$ $V_{GE} = 15V, R_{G} = 10\Omega,$	-	9	-	ns
Turn - off Delay Time	t _{d(off)}	$T_i = 25^{\circ}C$	-	107	-	
Fall Time	t _f	Inductive Load	-	55	-	
Turn - on Switching Loss	E _{on}	*E _{on} include diode reverse recovery	-	0.16	-	ml
Turn - off Switching Loss	E _{off}	,	-	0.24	-	mJ
Turn - on Delay Time	t _{d(on)}		-	34	-	
Rise Time	t _r	$I_{C} = 15A, V_{CC} = 400V,$ $V_{GF} = 15V, R_{G} = 10\Omega,$	-	10	-	20
Turn - off Delay Time	t _{d(off)}	$T_i = 175^{\circ}C$	-	139	-	ns
Fall Time	t _f	Inductive Load	-	76	-	
Turn - on Switching Loss	E _{on}	*E _{on} include diode reverse recovery	-	0.17	-	mJ
Turn - off Switching Loss	E _{off}		-	0.33	-	IIIJ
Reverse Bias Safe Operating Area	RBSOA	$\begin{split} I_{C} &= 120 \text{A}, \ V_{CC} = 520 \text{V}, \\ V_{P} &= 650 \text{V}, \ V_{GE} = 15 \text{V}, \\ R_{G} &= 100 \Omega, \ T_{j} = 175^{\circ} \text{C} \end{split}$	FU	ILL SQUA	RE	-

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•FRD Electrical Characteristics (at $T_j = 25^{\circ}C$ unless otherwise specified)

Parameter	Symbol	Conditions	Values			Lloit
	Symbol		Min.	Тур.	Max.	Unit
		I _F = 20A,				
Diode Forward Voltage	V_{F}	$T_j = 25^{\circ}C$	-	1.45	1.9	V
		$T_j = 175^{\circ}C$	-	1.55	-	
Diode Reverse Recovery Time	t _{rr}		-	87	-	ns
Diode Peak Reverse Recovery Current	I _{rr}	I _F = 15A, V _{CC} = 400V,	-	5.7	-	A
Diode Reverse Recovery Charge	Q _{rr}	di _F /dt = 200A/µs, T _j = 25°C	-	0.27	-	μC
Diode Reverse Recovery Energy	E _{rr}		-	11.0	-	μJ
Diode Reverse Recovery Time	t _{rr}	I _F = 15A, V _{CC} = 400V, di _F /dt = 200A/µs, T _j = 175°C	-	122	-	ns
Diode Peak Reverse Recovery Current	I _{rr}		-	6.9	-	A
Diode Reverse Recovery Charge	Q _{rr}		-	0.51	-	μC
Diode Reverse Recovery Energy	E _{rr}		-	26.5	_	μJ

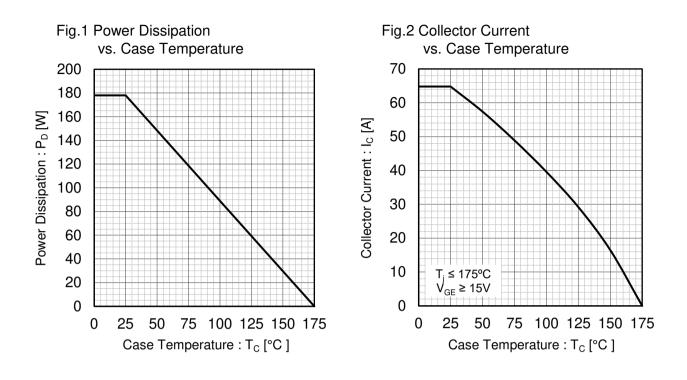
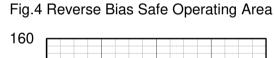
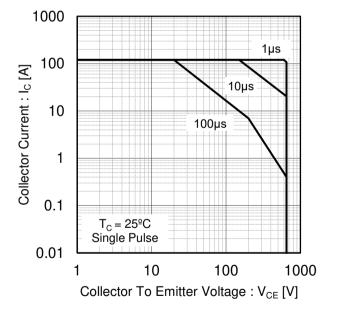
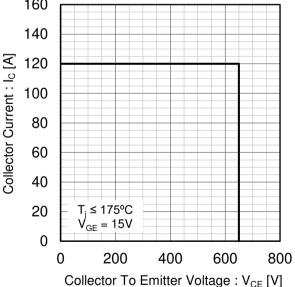
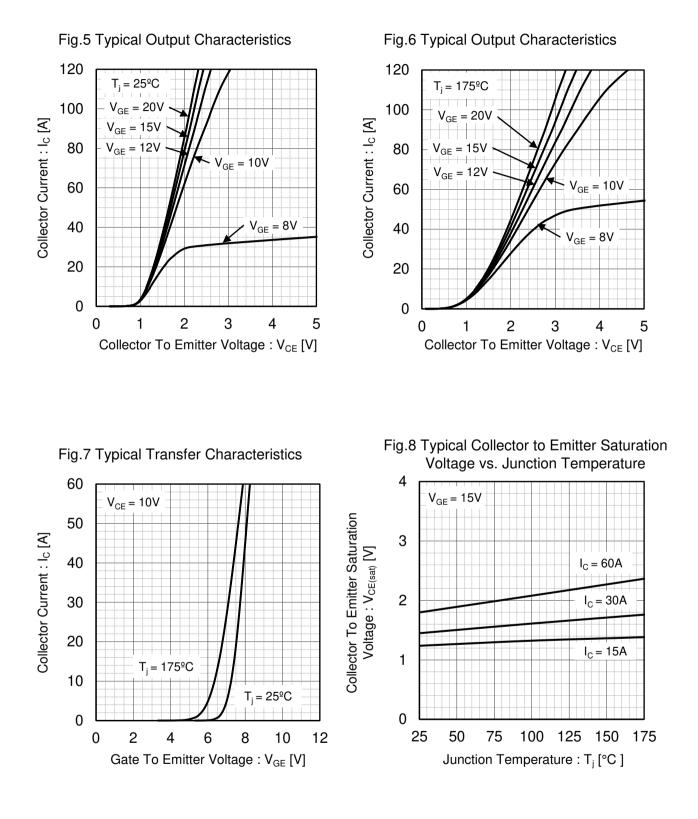


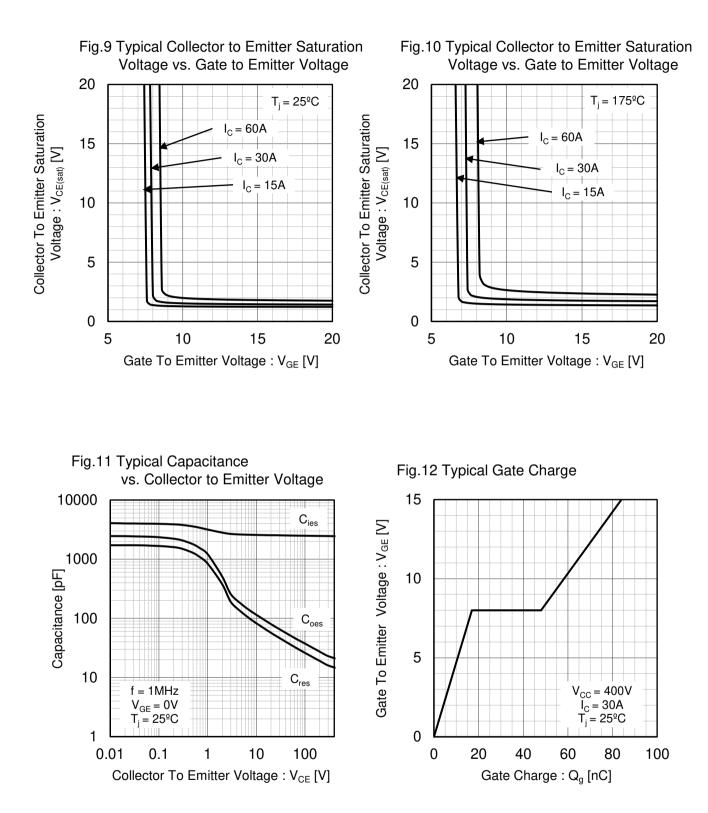
Fig.3 Forward Bias Safe Operating Area

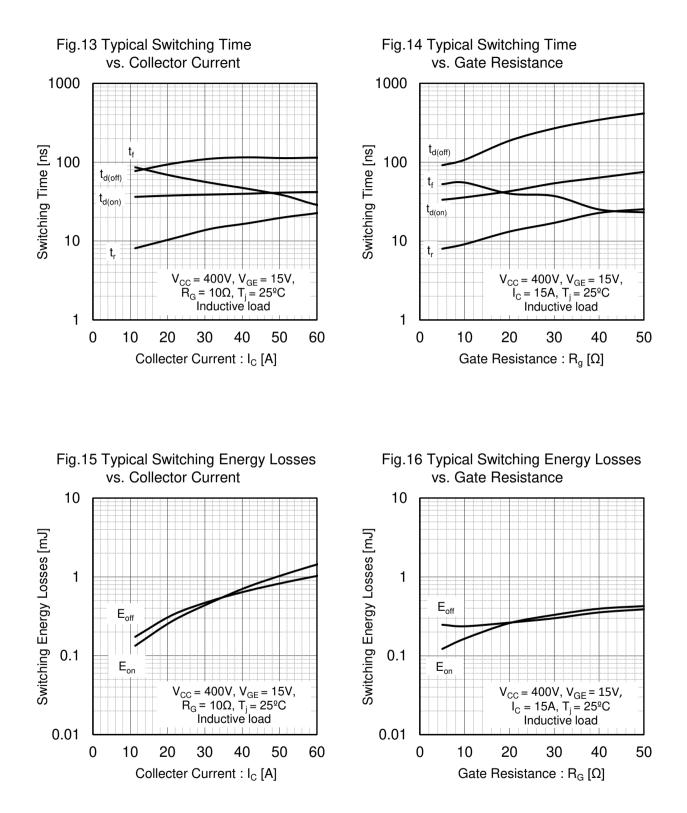


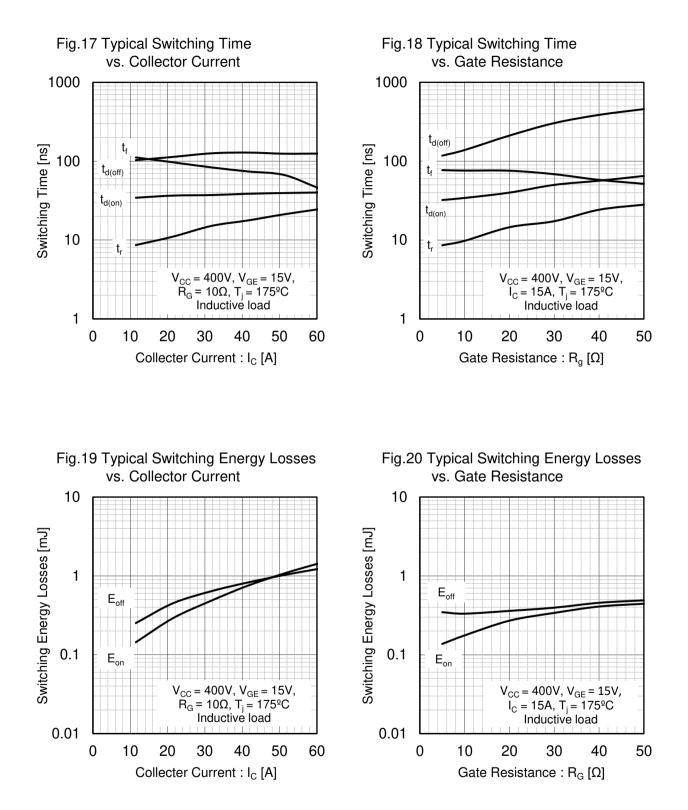


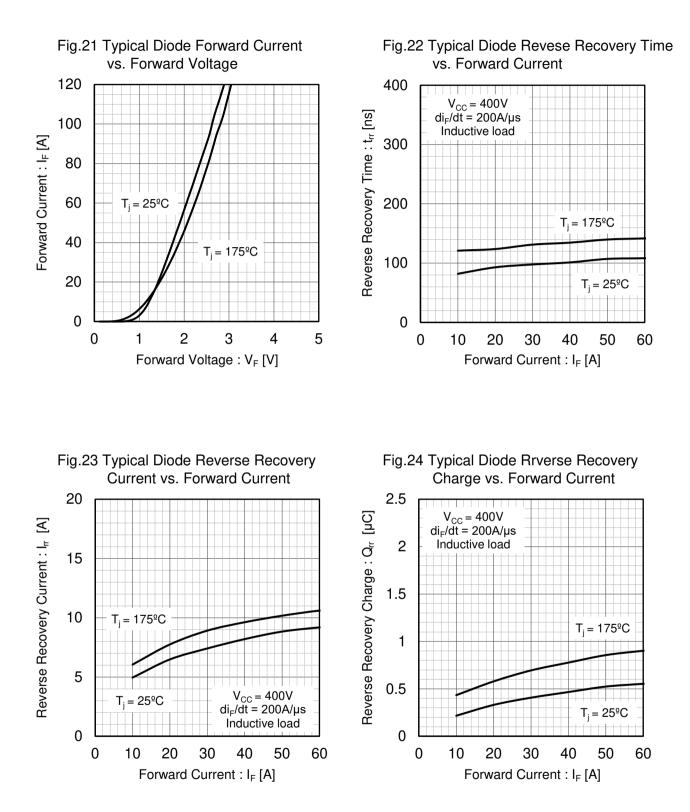












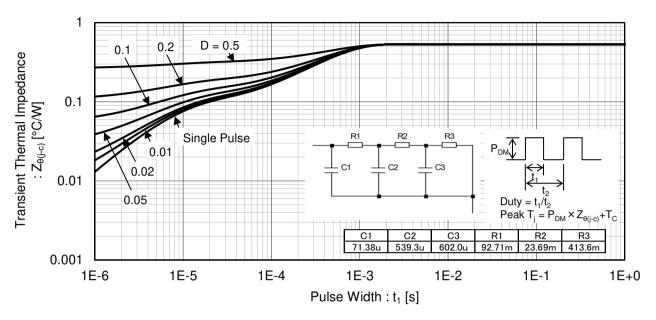
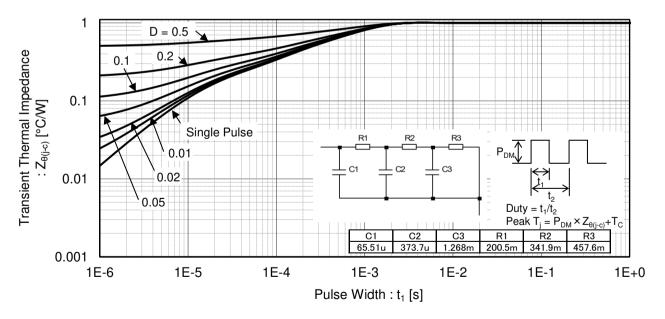


Fig.25 Typical IGBT Transient Thermal Impedance

Fig.26 Typical Diode Transient Thermal Impedance



Inductive Load Switching Circuit and Waveform

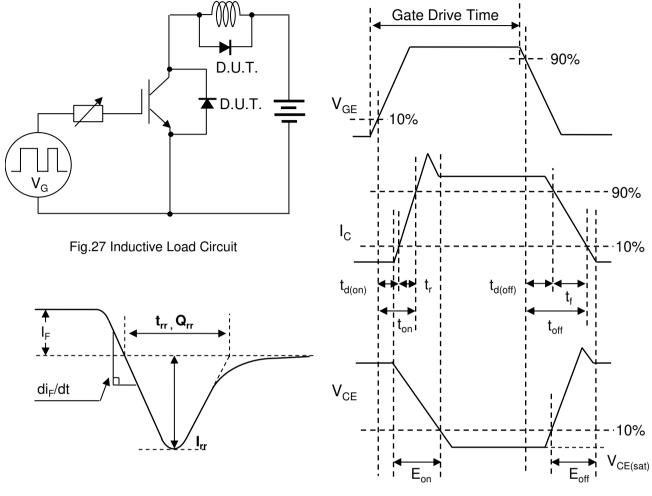


Fig.29 Diode Reverse Recovery Waveform

Fig.28 Inductive Load Waveform

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